Supporting Information

for

The effect of dry shear aligning of nanotube thin films on the photovoltaic performance of carbon nanotube–silicon solar cells

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Additional experimental information

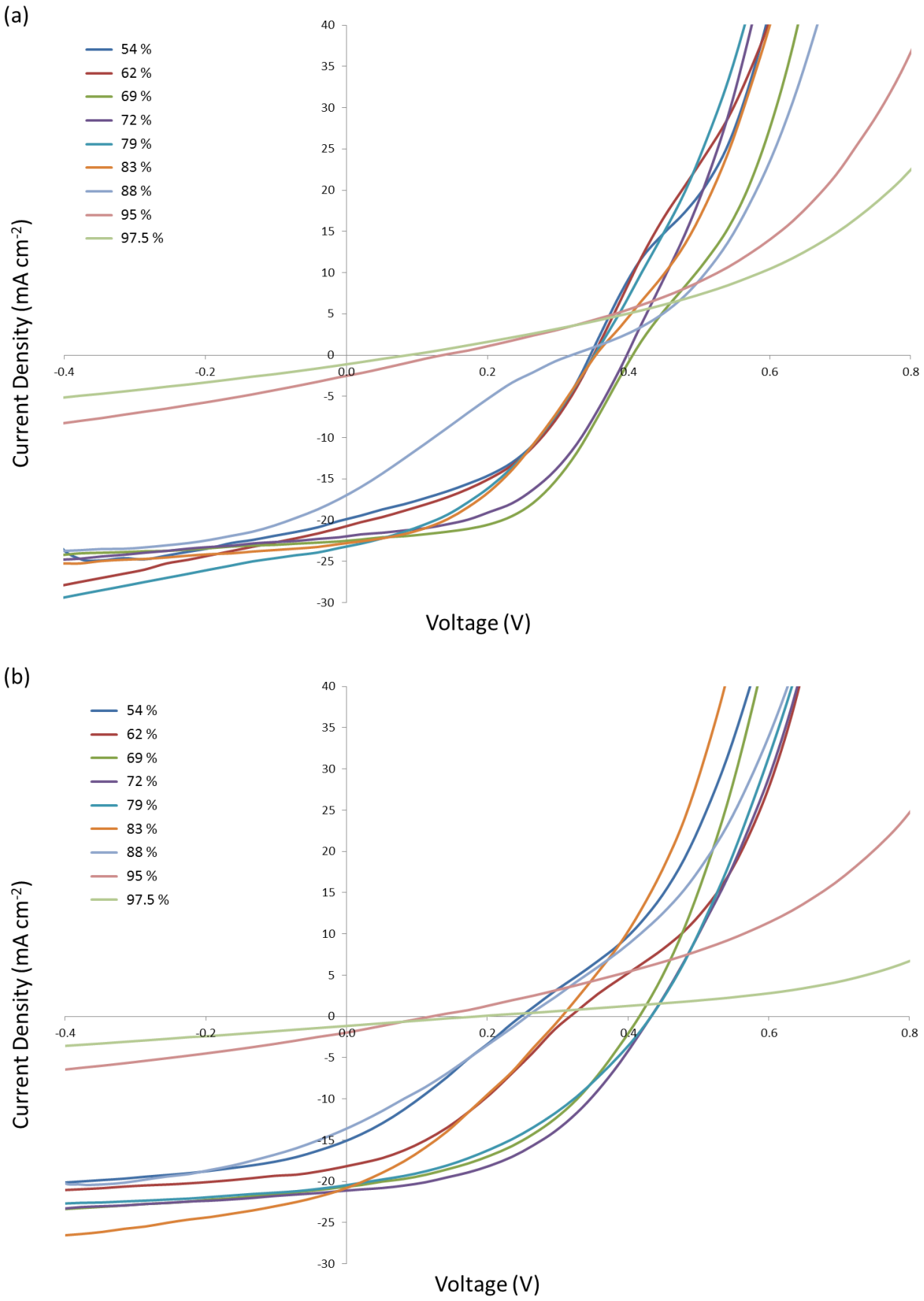

Figure S1: Variation of current density with voltage for devices made with different thicknesses (as measured by the transmittance @ 550 nm) of nanotube film using a) as prepared films or, b) dry shear aligned films. The parameters of open circuit voltage, short circuit current density, fill factor, and power conversion efficiency are summarised in Figure 3 of the main text.